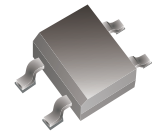


CDBHM220L-G Thru. CDBHM2100L-G

Reverse Voltage: 20 to 100 Volts

Forward Current: 2.0 Amp

RoHS Device

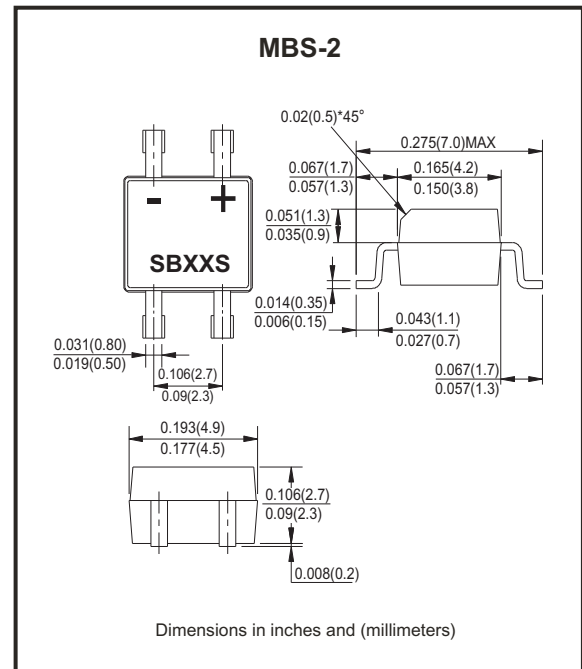


Features

- For surface mounted applications..
- Metal-Semiconductor junction with guarding.
- Epitaxial construction.
- Very low forward Voltage drop .
- High current capability
- Plastic material has UL flammability classification 94V-0
- For use in low voltage,high frequency inverters, free wheeling , and polarity protection applications.
- Pb free product.

Mechanical data

- Case: molded plastic.
- Polarity: Indicated by cathode band.
- Weight:0.125 gram(approx.).



xxx = Product type marking code

Maximum Rating And Electrical Characteristics

Rating at $T_A=25^{\circ}\text{C}$, unless otherwise noted.
Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

or capacitive load, surge current by 25%.

Parameter	Symbol	CDBHM 220L-G	CDBHM 230L-G	CDBHM 240L-G	CDBHM 250L-G	CDBHM 260L-G	CDBHM 280L-G	CDBHM 290L-G	CDBHM 2100L-G	Unit
	Marking	SB22S	SB23S	SB24S	SB25S	SB26S	SB28S	SB29S	SB210S	
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	20	30	40	50	60	80	90	100	V
Maximum RMS Voltage	V _{RMS}	14	21	28	35	42	56	63	70	V
Maximum DC Blocking Voltage	V _{DC}	20	30	40	50	60	80	90	100	V
Maximum Average Forward Rectified Current @T _L =100 °C	I _(AV)	2.0								A
Peak Forward Surge Current, 8.3ms single half sine-wave, superimposed on rated load (JEDEC Method)	I _{FSM}	50								A
Maximum Forward Voltage at 2.0A DC	V _F	0.55			0.70		0.85			V
Maximum DC Reverse Current @T _J =25 °C at Rated DC Blocking Voltage @T _J =100 °C	I _R	1.0 20								mA
Typical Junction Capacitance (Note 1)	C _J	125								pF
Typical Thermal Resistance (Note 2)	R _{θJA}	20								°C/W
Operating Temperature Range	T _J	-55 to +125								°C
Storage Temperature Range	T _{STG}	-55 to +150								°C

Notes: 1. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
2. Thermal resistance junction to lead.

Company reserves the right to improve product design , functions and reliability without notice.

REV: B

RATING AND CHARACTERISTIC CURVES (CDBHM220L-G Thru. CDBHM2100L-G)

FIG. 1 - FORWARD CURRENT DERATING CURVE

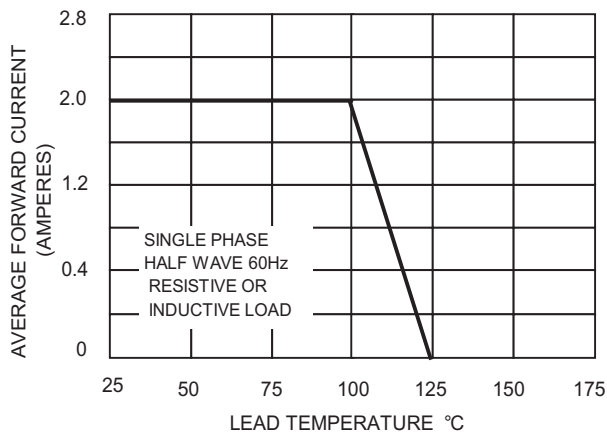


FIG. 2 - MAXIMUM NON-REPETITIVE SURGE CURRENT

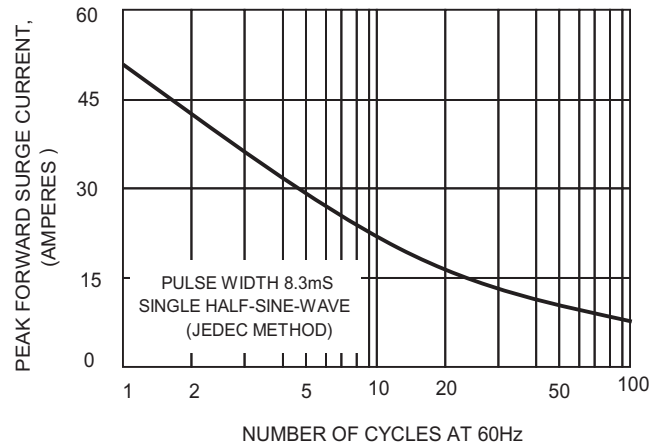


FIG.3-TYPICAL FORWARD CHARACTERISTICS

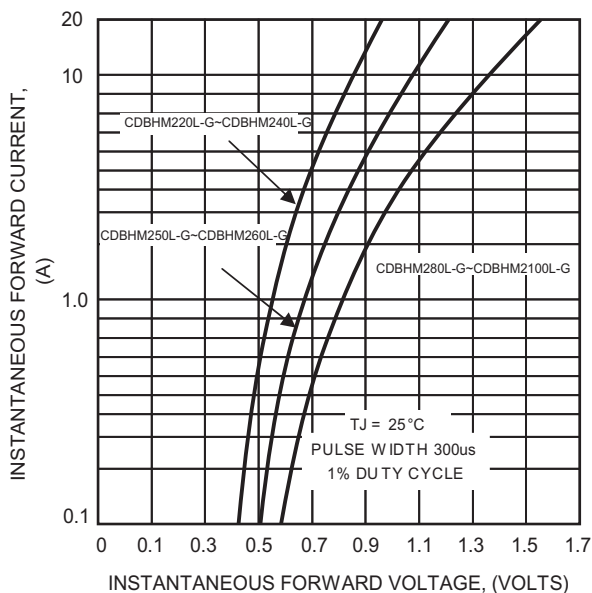


FIG.4-TYPICAL JUNCTION CAPACITANCE

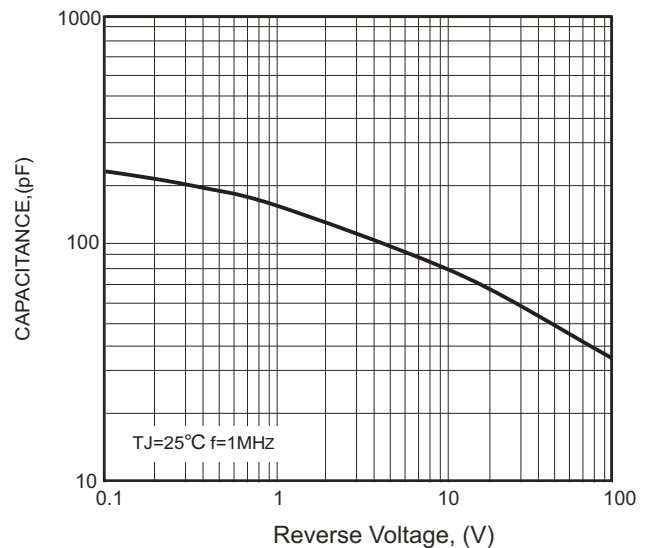
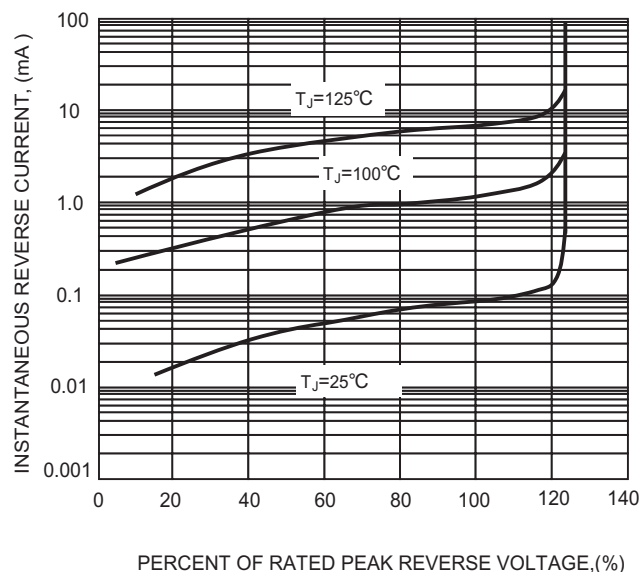
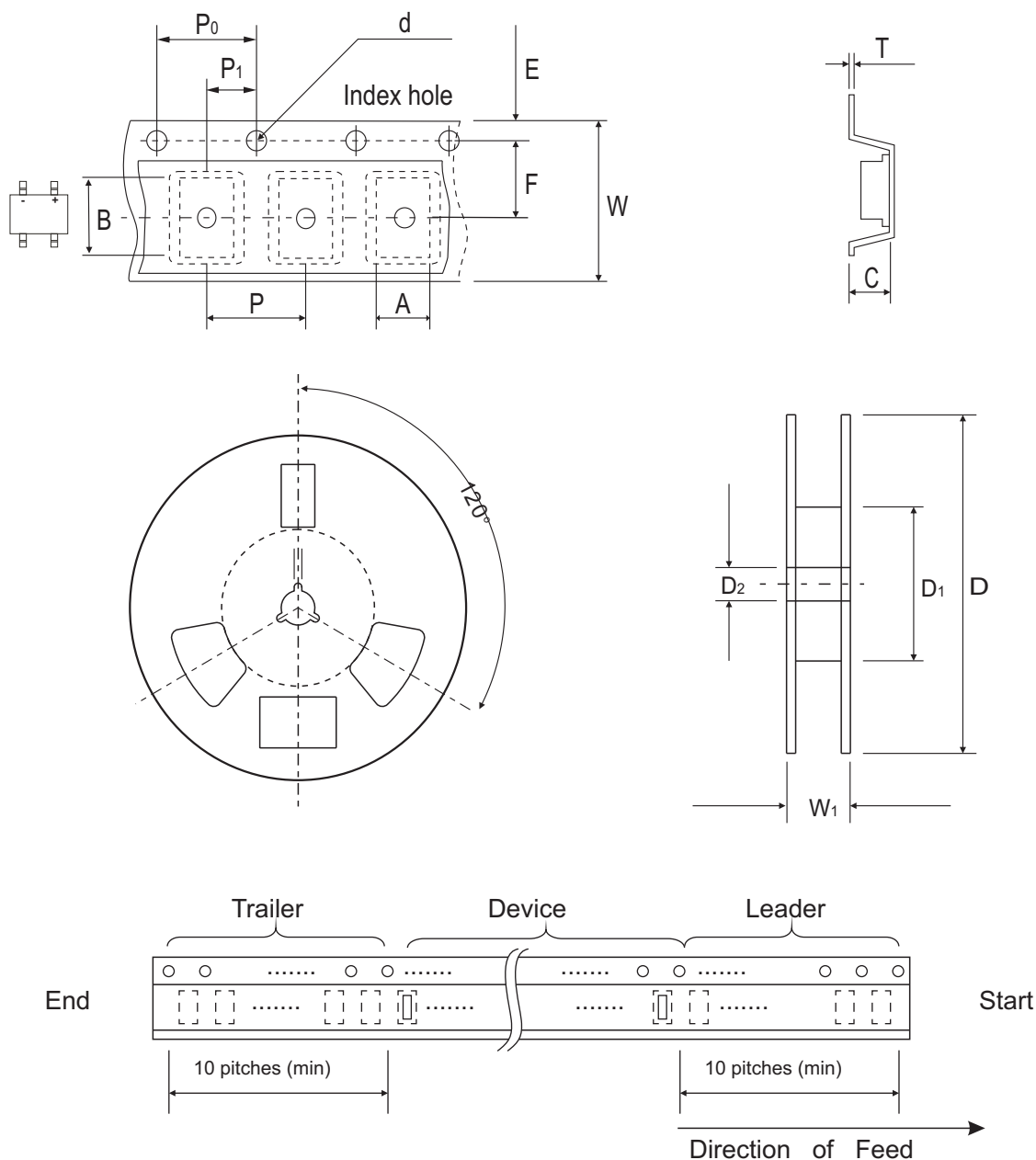


FIG.5-TYPICAL REVERSE CHARACTERISTICS



Reel Taping Specification

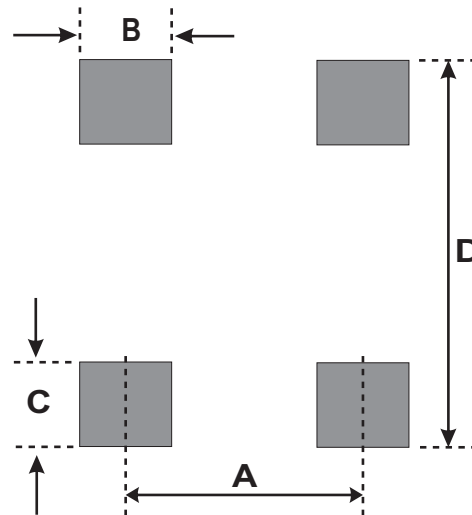


MBS-2	SYMBOL	A	B	C	d	D	D ₁	D ₂
	(mm)	4.90 ± 0.01	7.24 ± 0.10	3.33 ± 0.10	1.55 ± 0.10	330.0	50.0 MIN.	13.0 ± 0.20
	(inch)	0.93 ± 0.004	0.285 ± 0.004	0.131 ± 0.004	0.0610 ± 0.004	13.00	1.969 MIN.	0.512 ± 0.008

MBS-2	SYMBOL	E	F	P	P ₀	P ₁	W	W ₁
	(mm)	1.75 ± 0.10	5.50 ± 0.05	8.00 ± 0.10	4.00 ± 0.10	2.00 ± 0.05	12.00 ± 0.30	12.0~14.40
	(inch)	0.069 ± 0.004	0.217 ± 0.002	0.315 ± 0.004	0.157 ± 0.004	0.079 ± 0.002	0.472 ± 0.012	0.472~0.657

Suggested PAD Layout

SIZE	MBS-2	
	(mm)	(inch)
A	2.55 REF	0.100 REF
B	0.82 MIN	0.032MIN
C	0.92 MIN	0.036 MIN
D	7.00 MAX	0.276MAX



Standard Packaging

Case Type	REEL PACK	
	REEL (pcs)	Reel Size (inch)
MBS-2	3,000	13

Mouser Electronics

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